Contents STGW19NC60W

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STGW19NC60W Electrical ratings

1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{GE} = 0)	600	V
lc ⁽¹⁾	Continuous collector current at T _C = 25 °C	42	Α
lc ⁽¹⁾	Continuous collector current at T _C = 100 °C	23	Α
I _{CL} ⁽²⁾	Turn-off latching current	30	Α
V _{GE}	Gate-emitter voltage	±20	V
Ртот	Total dissipation at T _C = 25 °C	140	W
T _{stg}	Storage temperature range		°C
TJ	Operating junction temperature range	- 55 to 150	

Notes:

⁽¹⁾Calculated according to the iterative formula:

$$I_C(T_C) = \frac{T_{JMAX} - T_C}{R_{THJ-C} \times V_{CESAT(MAX)}(T_{J(max)} \times I_C(T_C))}$$

 $^{(2)}V_{CLAMP}$ = 80% (V_{CES}), V_{GE} = 15 V, R_G = 10 Ω , T_J = 150 °C

Table 3: Thermal data

Symbol	Parameter		Unit
R _{thj-case}	R _{thj-case} Thermal resistance junction-case max		
R _{thj-amb}	R _{thj-amb} Thermal resistance junction-ambient max		°C/W

2 Electrical characteristics

T_C = 25 °C unless otherwise specified

Table 4: Static

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)CES}	Collector-emitter breakdown voltage	V _{GE} = 0 V, I _C = 1 mA	600			٧
VCE(sat)	Collector-emitter saturation	V _{GE} = 15 V, I _C = 12 A		2.1	2.5	
	voltage	V _{GE} = 15 V, I _C = 12 A, T _J = 125 °C		1.8		V
$V_{GE(th)}$	Gate threshold voltage	$V_{CE} = V_{GE}, I_{C} = 250 \mu A$	3.75		5.75	V
I _{CES}		V _{GE} = 0 V, V _{CE} = 600 V			150	μΑ
	Collector cut-off current	V _{GE} = 0 V, V _{CE} = 600 V, T _C =125 °C ⁽¹⁾			1	mA
I _{GES}	Gate-emitter leakage current	V _{CE} = 0 V, V _{GE} = ± 20 V			±100	nΑ
g fs	Forward transconductance	V _{CE} = 15 V, I _C = 12 A		10		S

Notes:

Table 5: Dynamic

Table 6. Dynamic						
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C _{ies}	Input capacitance		-	1180	1	
Coes	Output capacitance	Output capacitance V _{CE} = 25 V, f = 1 MHz,		130	-	pF
Cres	Reverse transfer capacitance	V _{GE} = 0 V	1	26	1	Pi.
Qg	Total gate charge $V_{CE} = 390 \text{ V}, I_{C} = 12 \text{ A},$		ı	53	1	
Qge	Gate-emitter charge	V _{GE} = 15 V (see <i>Figure 16: "Gate charge</i>	-	10	-	nC
Qgc	Gate-collector charge	test circuit")	-	21	-	

⁽¹⁾Defined by design, not subject to production test.

Table 6: Switching on/off (inductive load)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)}	Turn-on delay time	V _{CC} = 390 V, I _C = 12 A,	-	25	-	ns
tr	Current rise time	V_{GE} = 15 V, R _G = 10 Ω (see Figure 17: "Switching	-	7	1	ns
(di/dt) _{on}	Turn-on current slope	waveform")		1600	-	A/µs
t _{d(on)}	Turn-on delay time	V _{CC} = 390 V, I _C = 12 A,	-	25	1	ns
tr	Current rise time	V_{GE} = 15 V, R _G = 10 Ω , T _C = 125°C (see <i>Figure 17: "Switching waveform"</i>)		8	1	ns
(di/dt) _{on}	Turn-on current slope			1400	-	A/µs
$t_r(V_{off})$	Off voltage rise time	V _{CC} = 390 V, I _C = 12 A,	-	22	-	ns
t _d (off)	Turn-off delay time	V_{GE} = 15 V, R _G = 10 Ω (see Figure 17: "Switching	-	90	-	ns
t _f	Current fall time	waveform")	-	43	-	ns
$t_r(V_{off})$	Off voltage rise time	V _{CC} = 390 V, I _C = 12 A,	-	47	1	ns
t _d (off)	Turn-off delay time	V_{GE} = 15 V, R_{G} = 10 Ω, T_{C} = 125°C (see <i>Figure 17:</i>	1	127	1	ns
t f	Current fall time	"Switching waveform")	-	77	-	ns

Table 7: Switching energy (inductive load)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
E _{on} (1)	Turn-on switching energy		-	81	1	μJ
E _{off} ⁽²⁾	Turn-off switching energy	$V_{CC} = 390 \text{ V}, I_C = 12 \text{ A},$	-	125	1	μJ
Ets	Total switching energy	R _G = 10 Ω, V _{GE} = 15 V (see <i>Figure 17: "Switching</i>	-	206	1	μJ
E _{on} (1)	Turn-on switching energy	waveform")	-	161	-	μJ
E _{off} ⁽²⁾	Turn-off switching energy		-	255	1	μJ
Ets	Total switching energy	$V_{CC} = 390 \text{ V, } I_{C} = 12 \text{ A,}$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V,}$		416	-	μJ

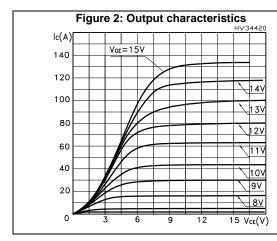
Notes:

47/

 $^{^{(1)}\}mbox{Including}$ the reverse recovery of the external diode. The diode is the same of the co-packed STGW19NC60WD.

⁽²⁾including the tail of the collector current.

2.2 Electrical characteristics (curves)



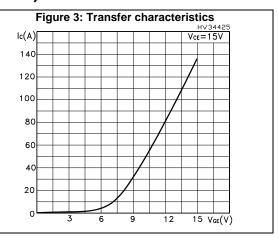


Figure 4: Transconductance

HV34460

VCE=15V

15

12

9

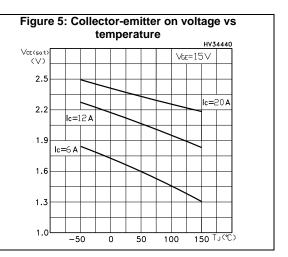
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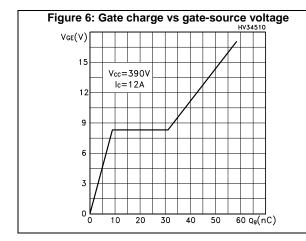
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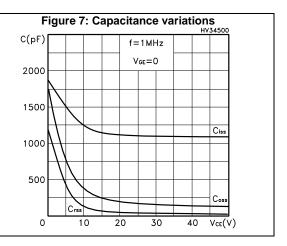
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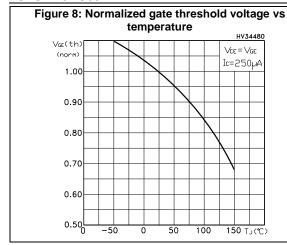
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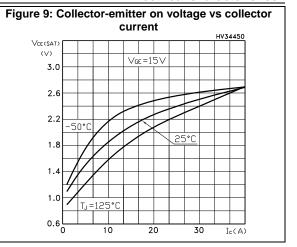
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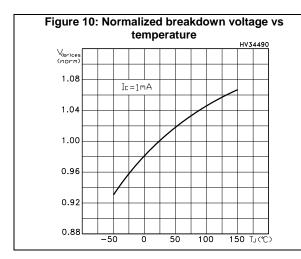


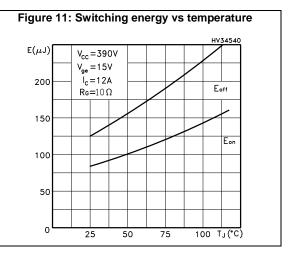


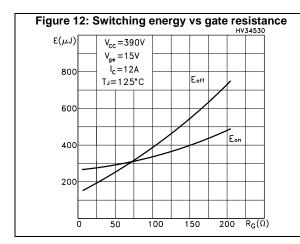


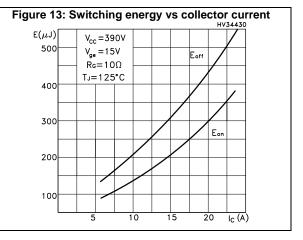






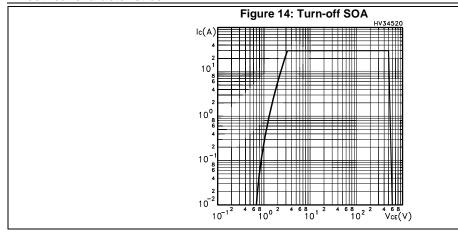






Electrical characteristics

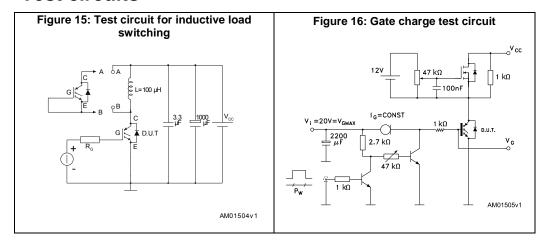
STGW19NC60W

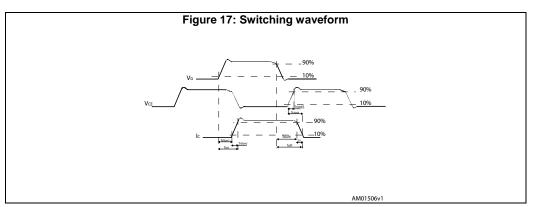


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STGW19NC60W Test circuits

3 Test circuits





4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

4.1 TO-247 package information

HEAT-SINK PLANE

L2

L1

L2

L3

BACK VIEW

0075325_8

Figure 18: TO-247 package outline

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Table 8: TO-247 package mechanical data

		mm	
Dim.	Min.	Тур.	Max.
А	4.85		5.15
A1	2.20		2.60
b	1.0		1.40
b1	2.0		2.40
b2	3.0		3.40
С	0.40		0.80
D	19.85		20.15
E	15.45		15.75
е	5.30	5.45	5.60
L	14.20		14.80
L1	3.70		4.30
L2		18.50	
ØP	3.55		3.65
ØR	4.50		5.50
S	5.30	5.50	5.70

Revision history STGW19NC60W

5 Revision history

Table 9: Document revision history

Date	Revision	Changes
04-Oct-2006	1	Initial release.
08-May-2007	2	Modified value on Table 2
20-Nov-2008	3	Inserted packages: D2PAK and TO-247
07-Nov-2016	4	The part numbers STGB19NC60W and STGP19NC60W have been moved to a separate datasheet Modified: Table 2: "Absolute maximum ratings", Table 4: "Static" and Table 7: "Switching energy (inductive load)" Minor text changes

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